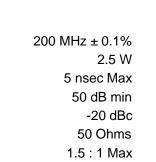
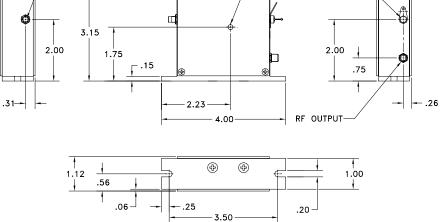
SPECIFICATIONS OUTLINE DRAWING Modulation Input MOD. INPUT 50 Ohms Input Impedance RF LEVEL +Vcc Analog Input (SMC) 0 to +1.0 VDC RF Output A 3.15 Center Frequency (Fc) 200 MHz ± 0.1% 2.00 Output Power (SMA Female) 1.75 2.5 W .15 **Rise/Fall Time** 5 nsec Max **RF** Contrast Ratio

Harmonic Distortion **Output Impedance Output VSWR** Power Supply Voltage +24 V @ 775 mA





Document

10/18/10

Control

Notes:

1. Output power factory set to 2.5 W at 1.0 Volt input. Power stability less than 5% over the heat sink's ambient temperature range of 0 - 40° C, after 5 minute warm-up.

2. When calculating the contrast ratio, it is understood that only the power of the 200 MHz fundamental shall be used. The higher harmonics have no effect on the AO modulator's performance.

3. RoHS compliant.



DISCLOSED IN WHO CONTRACTED REPR	LE OR IN	DPERTY OF CRYSTAL I PART OTHER THAN E TIVES AND DISTRIBU ED REPRESENTATIVE	BY EMPLOYEES OF TERS. ANY EXCEP	CRYSTA	AL TECHNOLO	OGY AND ITS
TOLERANCES: .XX ±.01 .XXX ±.005	DR	T. Moon 10/4/2010	👻 Crystal Technology, Inc.			
	снк		AODR 1200AF-AINA-2.5 HCR			
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Compliant	APP		PART NUMBER: 97-02910-	04	B B	1 of 1